

# XBS013S15R-G

Schottky Barrier Diode, 100mA, 30V Type

## FEATURES

Forward Voltage	: $V_F=0.71V$ (TYP.)
Forward Current	: $I_{F(AV)}=100mA$
Repetitive Peak Reverse Voltage	: $V_{RM}=30V$
Environmentally Friendly	: EU RoHS Compliant, Pb Free

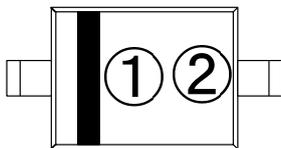
## ABSOLUTE MAXIMUM RATING

$T_a=25^\circ C$

PARAMETER	SYMBOL	RATINGS	UNIT
Repetitive Peak Reverse Voltage	$V_{RM}$	30	V
Reverse Voltage (DC)	$V_R$	30	V
Forward Current (Average)	$I_{F(AV)}$	100	mA
Non Continuous Forward Surge Current <sup>*1</sup>	$I_{FSM}$	0.6	A
Junction Temperature	$T_j$	125	$^\circ C$
Storage Temperature Range	$T_{stg}$	-55~+150	$^\circ C$

\*1 : Non continuous high amplitude 60Hz half -sine wave.

## MARKING RULE



- ①: 0 (Product Number)  
②: Assembly Lot Number

## PRODUCT NAME

PRODUCT NAME	DESCRIPTION
XBS013S15R	SOD-523
XBS013S15R-G	SOD-523 (Halogen & Antimony free)

\* The "-G" suffix indicates that the products are Halogen and Antimony free as well as being fully RoHS compliant.

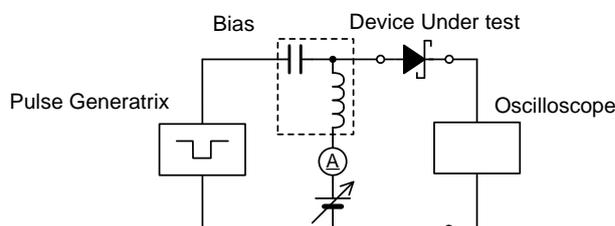
\* The device orientation is fixed in its embossed tape pocket.

## ELECTRICAL CHARACTERISTICS

$T_a=25^\circ C$

PARAMETER	SYMBOL	TEST CONDITIONS	LIMITS			UNIT
			MIN.	TYP.	MAX.	
Forward Voltage	$V_{F1}$	$I_F=1mA$	-	0.31	-	V
	$V_{F2}$	$I_F=100mA$	-	0.71	1	V
Reverse Current	$I_R$	$V_R=25V$	-	-	2	$\mu A$
Inter-Terminal Capacity	$C_t$	$V_R=0V, f=1MHz$	-	6	-	pF
Reverse Recovery Time <sup>*2</sup>	$t_{rr}$	$I_F=I_R=10mA, i_{rr}=1mA$	-	2	-	ns

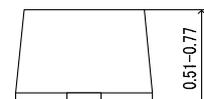
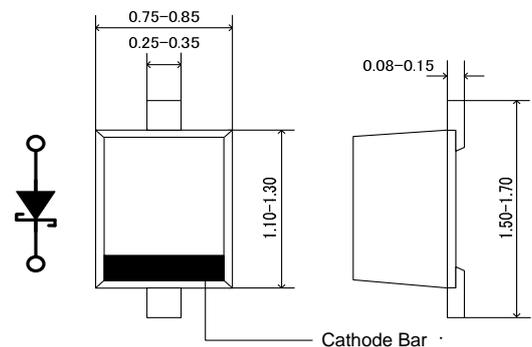
\*2 :  $t_{rr}$  measurement circuit



## APPLICATIONS

- Low Current Rectification

## PACKAGING INFORMATION

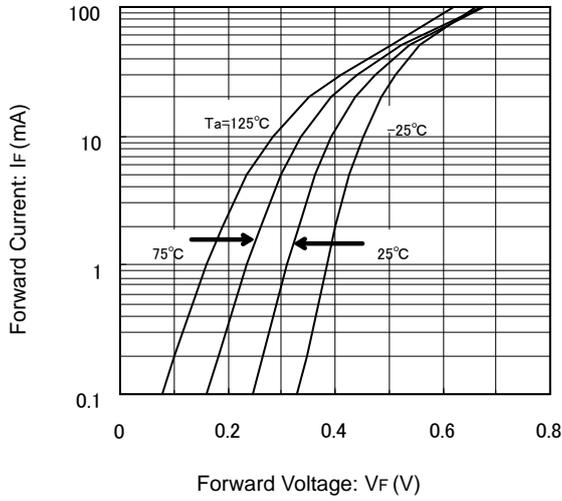


SOD-523

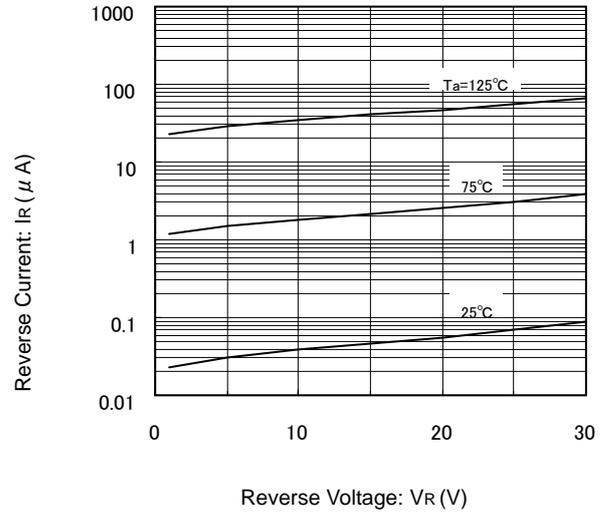
Unit : mm

## TYPICAL PERFORMANCE CHARACTERISTICS

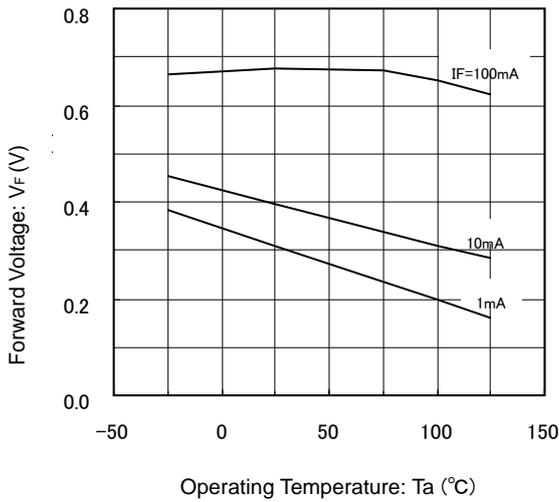
(1) Forward Current vs. Forward Voltage



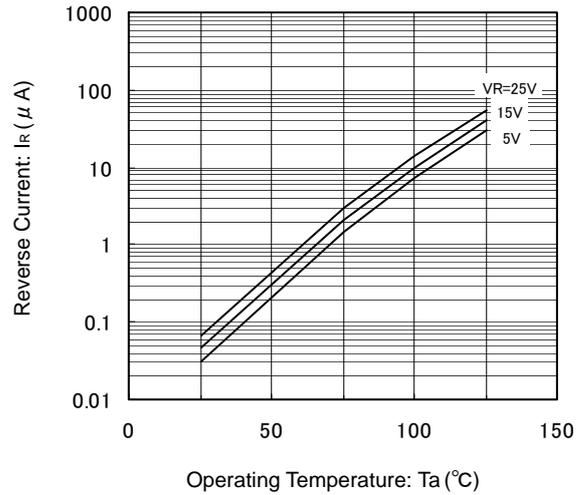
(2) Reverse Current vs. Reverse Voltage



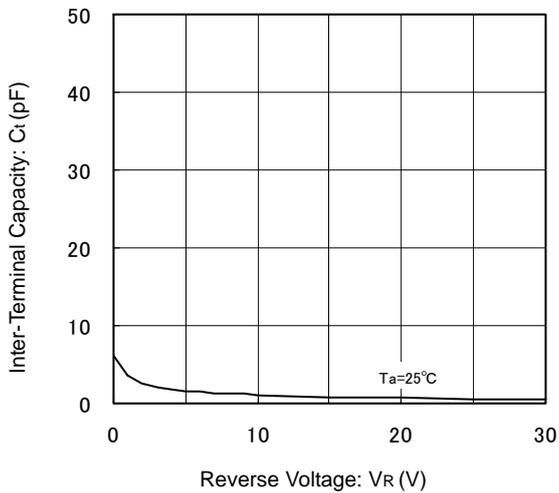
(3) Forward Voltage vs. Operating Temperature



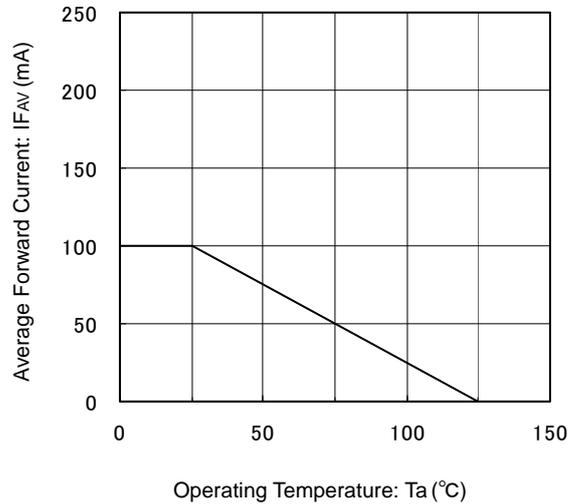
(4) Reverse Current vs. Operating Temperature



(5) Inter-Terminal Capacity vs. Reverse Voltage



(6) Average Forward Current vs. Operating Temperature



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